

LMV821 SINGLE, LMV822 DUAL, LMV824 QUAD LOW-VOLTAGE RAIL-TO-RAIL OUTPUT OPERATIONAL AMPLIFIERS

FEATURES

- 2.5-V, 2.7-V, and 5-V Performance
- -40°C to 125°C Operation
- No Crossover Distortion
- Low Supply Current at V_{CC+} = 5 V:
 - LMV821 0.3 mA Typ
 - LMV822 0.5 mA Typ
 - LMV824 1 mA Typ
- Rail-to-Rail Output Swing
- Gain Bandwidth of 6 MHz Typ at 5 V
- Slew Rate of 1.9 V/μs Typ at 5 V

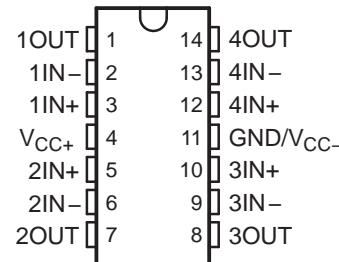
DESCRIPTION

The LMV821 single, LMV822 dual, and LMV824 quad devices are low-voltage (2.5 V to 5.5 V), low-power commodity operational amplifiers. Electrical characteristics are very similar to the LMV3xx operational amplifiers (low supply current, rail-to-rail outputs, input common-mode range that includes ground). However, the LMV8xx devices offer a higher bandwidth (6 MHz typical) and faster slew rate (1.9 V/μs typical).

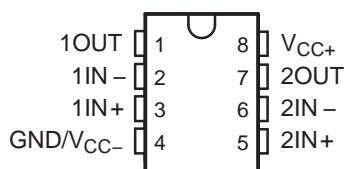
The LMV8xx devices are cost-effective solutions for applications requiring low-voltage/low-power operation and space-saving considerations. The LMV821 is available in the ultra-small DCK package, which is approximately half the size of SOT-23-5. The DCK package saves space on printed circuit boards and enables the design of small portable electronic devices (cordless and cellular phones, laptops, PDAs, PCMIA). It also allows the designer to place the device closer to the signal source to reduce noise pickup and increase signal integrity.

The LMV8xx devices are characterized for operation from -40°C to 85°C. The LMV8xxL devices are characterized for operation from -40°C to 125°C.

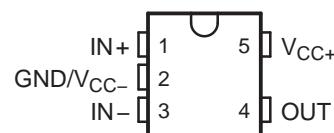
**LMV824 D, DGV, OR PW PACKAGE
(TOP VIEW)**



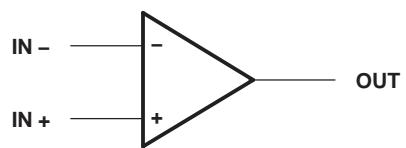
**LMV822 D OR DGK PACKAGE
(TOP VIEW)**



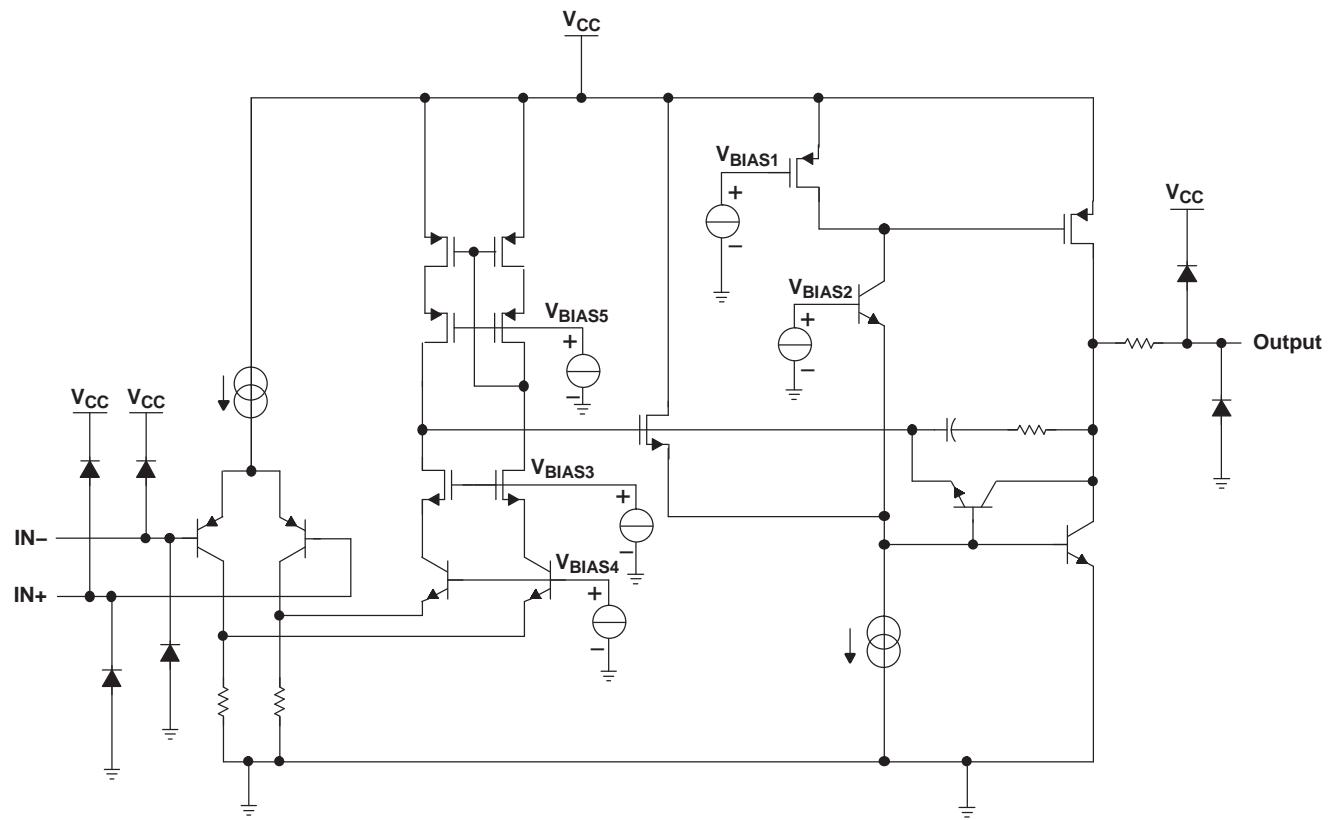
**LMV821 DBV OR DCK PACKAGE
(TOP VIEW)**



SYMBOL (EACH AMPLIFIER)



LMV824 SIMPLIFIED SCHEMATIC



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage ⁽²⁾			5.5	V
V _{ID}	Differential input voltage ⁽³⁾			±V _{CC}	V
V _I	Input voltage range (either input)		V _{CC-}	V _{CC+}	V
Duration of output short circuit (one amplifier) to ground ⁽⁴⁾	At or below T _A = 25°C, V _{CC} ≤ 5.5 V		Unlimited		
θ _{JA}	D package	8 pin	97		°C/W
		14 pin	86		
	DBV package		206		
	DCK package		252		
	DGK package		172		
	DGV package		127		
	PW package		113		
T _J	Operating virtual junction temperature		150		°C
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at IN+ with respect to IN-.
- (4) Short circuits from outputs to V_{CC} can cause excessive heating and eventual destruction.
- (5) Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is P_D = (T_{J(max)} - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions

			MIN	MAX	UNIT
V _{CC}	Supply voltage (single-supply operation)		2.5	5	V
T _A	Operating free-air temperature	LMV8xxL	-40	125	°C
		LMV8xx	-40	85	

LMV8xx 2.5-V Electrical Characteristics

$V_{CC+} = 2.5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_O = 1.25 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{CC+} = 2.5 \text{ V}$, $R_L = 600 \Omega$ to 1.25 V	25°C		1	3.5	mV
		-40°C to 85°C			4	
V_O Output swing	$V_{CC+} = 2.5 \text{ V}$, $R_L = 600 \Omega$ to 1.25 V	High level	25°C	2.3	2.37	V
			-40°C to 85°C	2.2		
		Low level	25°C		0.13 0.2	
			-40°C to 85°C		0.3	
	$V_{CC+} = 2.5 \text{ V}$, $R_L = 2 \text{ k}\Omega$ to 1.25 V	High level	25°C	2.4	2.46	
			-40°C to 85°C	2.3		
		Low level	25°C		0.08 0.12	
			-40°C to 85°C		0.2	

LMV8xxI 2.5-V Electrical Characteristics

$V_{CC+} = 2.5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_O = 1.25 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage	$V_{CC+} = 2.5 \text{ V}$, $R_L = 600 \Omega$ to 1.25 V	25°C		1	3.5	mV
		-40°C to 125°C			5.5	
V_O Output swing	$V_{CC+} = 2.5 \text{ V}$, $R_L = 600 \Omega$ to 1.25 V	High level	25°C	2.28	2.37	V
			-40°C to 125°C	2.18		
		Low level	25°C		0.13 0.22	
			-40°C to 125°C		0.32	
	$V_{CC+} = 2.5 \text{ V}$, $R_L = 2 \text{ k}\Omega$ to 1.25 V	High level	25°C	2.38	2.46	
			-40°C to 125°C	2.28		
		Low level	25°C		0.08 0.14	
			-40°C to 125°C		0.22	

LMV8xx 2.7-V Electrical Characteristics
 $V_{CC+} = 2.7 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_O = 1.35 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C		1	3.5	mV
		-40°C to 85°C			4	
α_{VIO} Average temperature coefficient of input offset voltage		25°C		1		μV/°C
I_{IB} Input bias current		25°C		30	90	nA
		-40°C to 85°C			140	
I_{IO} Input offset current		25°C		0.5	30	nA
		-40°C to 85°C			50	
CMRR Common-mode rejection ratio	$V_{IC} = 0 \text{ to } 1.7 \text{ V}$	25°C	70	85		dB
		-40°C to 85°C	68			
$+k_{SVR}$ Positive supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V to } 4 \text{ V}$, $V_{CC-} = -1 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	75	85		dB
		-40°C to 85°C	70			
$-k_{SVR}$ Negative supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V}$, $V_{CC-} = -1 \text{ V to } -3.3 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	73	85		dB
		-40°C to 85°C	70			
V_{ICR} Common-mode input voltage range	$CMRR \geq 50 \text{ dB}$	25°C	-0.2 to 1.9	-0.3 to 2		V
A_V Large-signal voltage amplification	$R_L = 600 \Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 2.2 \text{ V}$	Sourcing	25°C	90	100	dB
			-40°C to 85°C	85		
	$R_L = 600 \Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	85	90	
			-40°C to 85°C	80		
	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 2.2 \text{ V}$	Sourcing	25°C	95	100	
			-40°C to 85°C	90		
	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	90	95	
			-40°C to 85°C	85		
V_O Output swing	$V_{CC+} = 2.7 \text{ V}$, $R_L = 600 \Omega \text{ to } 1.35 \text{ V}$	High level	25°C	2.5	2.58	V
			-40°C to 85°C	2.4		
		Low level	25°C		0.13 0.2	
			-40°C to 85°C		0.3	
	$V_{CC+} = 2.7 \text{ V}$, $R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	High level	25°C	2.6	2.66	
			-40°C to 85°C	2.5		
		Low level	25°C		0.08 0.12	
			-40°C to 85°C		0.2	
I_O Output current	$V_O = 0 \text{ V}$	Sourcing	25°C	12	16	mA
	$V_O = 2.7 \text{ V}$	Sinking	25°C	12	26	
I_{CC} Supply current	LMV821		25°C		0.22 0.3	mA
			-40°C to 85°C		0.5	
	LMV822 (both amplifiers)		25°C		0.45 0.6	
			-40°C to 85°C		0.8	
	LMV824 (all four amplifiers)		25°C		0.72 1	
			-40°C to 85°C		1.2	

LMV8xx 2.7-V Electrical Characteristics (continued)

$V_{CC+} = 2.7 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_O = 1.35 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
SR Slew rate ⁽¹⁾		25°C		1.7		V/ μ s
GBW Gain bandwidth product	⁽²⁾	25°C		6		MHz
Φ_m Phase margin	⁽²⁾	25°C		60		deg
Gain margin	⁽²⁾	25°C		8.6		dB
Amplifier-to-amplifier isolation	$V_{CC+} = 5 \text{ V}$, $R_L = 100 \text{ k}\Omega$ to 2.5 V ⁽³⁾	25°C		135		dB
V_n Equivalent input noise voltage	f = 1 kHz, $V_{IC} = 1 \text{ V}$	25°C		45		nV/ $\sqrt{\text{Hz}}$
I_n Equivalent input noise current	f = 1 kHz	25°C		0.18		pA/ $\sqrt{\text{Hz}}$
THD Total harmonic distortion	f = 1 kHz, $A_V = -2$, $R_L = 10 \text{ k}\Omega$, $V_O = 4.1 \text{ V}_{\text{p-p}}$	25°C		0.01		%

(1) Connected as voltage follower with 1-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22 \text{ pF}$

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{\text{p-p}}$

LMV8xxI 2.7-V Electrical Characteristics
 $V_{CC+} = 2.7 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 1 \text{ V}$, $V_O = 1.35 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C		1	3.5	mV
		-40°C to 125°C			5.5	
α_{VIO} Average temperature coefficient of input offset voltage		25°C		1		µV/°C
I_{IB} Input bias current		25°C		30	90	nA
		-40°C to 125°C			140	
I_{IO} Input offset current		25°C		0.5	30	nA
		-40°C to 125°C			50	
CMRR Common-mode rejection ratio	$V_{IC} = 0 \text{ to } 1.7 \text{ V}$	25°C	70	85		dB
		-40°C to 125°C	68			
$+k_{SVR}$ Positive supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V to } 4 \text{ V}$, $V_{CC-} = -1 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	75	85		dB
		-40°C to 125°C	70			
$-k_{SVR}$ Negative supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V}$, $V_{CC-} = -1 \text{ V to } -3.3 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	73	85		dB
		-40°C to 125°C	70			
V_{ICR} Common-mode input voltage range	$CMRR \geq 50 \text{ dB}$	25°C	-0.2 to 1.9	-0.3 to 2		V
A_V Large-signal voltage amplification	$R_L = 600 \Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 2.2 \text{ V}$	Sourcing	25°C	90	100	dB
			-40°C to 125°C	85		
	$R_L = 600 \Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	85	90	
			-40°C to 125°C	80		
	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 2.2 \text{ V}$	Sourcing	25°C	95	100	
			-40°C to 125°C	90		
	$R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$, $V_O = 1.35 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	90	95	
			-40°C to 125°C	85		
V_O Output swing	$V_{CC+} = 2.7 \text{ V}$, $R_L = 600 \Omega \text{ to } 1.35 \text{ V}$	High level	25°C	2.5	2.58	V
			-40°C to 125°C	2.4		
		Low level	25°C		0.13 0.2	
			-40°C to 125°C		0.3	
	$V_{CC+} = 2.7 \text{ V}$, $R_L = 2 \text{ k}\Omega \text{ to } 1.35 \text{ V}$	High level	25°C	2.6	2.66	
			-40°C to 125°C	2.5		
		Low level	25°C		0.08 0.12	
			-40°C to 125°C		0.2	
I_O Output current	$V_O = 0 \text{ V}$	Sourcing	25°C	12	16	mA
	$V_O = 2.7 \text{ V}$	Sinking	25°C	12	26	
I_{CC} Supply current	LMV821		25°C		0.22 0.3	mA
			-40°C to 125°C		0.5	
	LMV822 (both amplifiers)		25°C		0.45 0.6	
			-40°C to 125°C		0.8	
	LMV824 (all four amplifiers)		25°C		0.72 1	
			-40°C to 125°C		1.2	

LMV8xxI 2.7-V Electrical Characteristics (continued)

$V_{CC+} = 2.7$ V, $V_{CC-} = 0$ V, $V_{IC} = 1$ V, $V_O = 1.35$ V, and $R_L > 1$ M Ω (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
SR Slew rate ⁽¹⁾		25°C		1.7		V/ μ s
GBW Gain bandwidth product	(2)	25°C		6		MHz
Φ_m Phase margin	(2)	25°C		60		deg
Gain margin	(2)	25°C		8.6		dB
Amplifier-to-amplifier isolation	$V_{CC+} = 5$ V, $R_L = 100$ k Ω to 2.5 V ⁽³⁾	25°C		135		dB
V_n Equivalent input noise voltage	$f = 1$ kHz, $V_{IC} = 1$ V	25°C		45		nV/ $\sqrt{\text{Hz}}$
I_n Equivalent input noise current	$f = 1$ kHz	25°C		0.18		pA/ $\sqrt{\text{Hz}}$
THD Total harmonic distortion	$f = 1$ kHz, $A_V = -2$, $R_L = 10$ k Ω , $V_O = 4.1$ V _{p-p}	25°C		0.01		%

(1) Connected as voltage follower with 1-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22$ pF

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3$ V_{p-p}

LMV8xx 5-V Electrical Characteristics
 $V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 2 \text{ V}$, $V_O = 2.5 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
V_{IO} Input offset voltage		25°C		1	3.5	mV
		-40°C to 85°C			4	
α_{VIO} Average temperature coefficient of input offset voltage		25°C		1		µV/°C
I_{IB} Input bias current		25°C		40	100	nA
		-40°C to 85°C			150	
I_{IO} Input offset current		25°C		0.5	30	nA
		-40°C to 85°C			50	
CMRR Common-mode rejection ratio	$V_{IC} = 0 \text{ to } 4 \text{ V}$	25°C	72	90		dB
		-40°C to 85°C	70			
$+k_{SVR}$ Positive supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V to } 4 \text{ V}$, $V_{CC-} = -1 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	75	85		dB
		-40°C to 85°C	70			
$-k_{SVR}$ Negative supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V}$, $V_{CC-} = -1 \text{ V to } -3.3 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	73	85		dB
		-40°C to 85°C	70			
V_{ICR} Common-mode input voltage range	$CMRR \geq 50 \text{ dB}$	25°C	-0.2 to 4.2	-0.3 to 4.3		V
A_V Large-signal voltage amplification	$R_L = 600 \Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	25°C	95	105	dB
			-40°C to 85°C	90		
	$R_L = 600 \Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	95	105	
			-40°C to 85°C	90		
	$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	25°C	95	105	
			-40°C to 85°C	90		
	$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	95	105	
			-40°C to 85°C	90		
V_O Output swing	$V_{CC+} = 5 \text{ V}$, $R_L = 600 \Omega \text{ to } 2.5 \text{ V}$	High level	25°C	4.75	4.84	V
			-40°C to 85°C	4.7		
		Low level	25°C	0.17	0.25	
			-40°C to 85°C		0.3	
	$V_{CC+} = 5 \text{ V}$, $R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$	High level	25°C	4.85	4.9	
			-40°C to 85°C	4.8		
		Low level	25°C	0.1	0.15	
			-40°C to 85°C		0.2	
I_O Output current	$V_O = 0 \text{ V}$	Sourcing	25°C	20	45	mA
			-40°C to 85°C	15		
	$V_O = 5 \text{ V}$	Sinking	25°C	20	40	
			-40°C to 85°C	15		
I_{CC} Supply current	LMV821		25°C		0.3	mA
			-40°C to 85°C		0.6	
	LMV822 (both amplifiers)		25°C		0.5	
			-40°C to 85°C		0.9	
	LMV824 (all four amplifiers)		25°C		1	
			-40°C to 85°C		1.5	

LMV8xx 5-V Electrical Characteristics (continued)

$V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 2 \text{ V}$, $V_O = 2.5 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
SR Slew rate	$V_{CC+} = 5 \text{ V}$ ⁽¹⁾	25°C	1.4	1.9		V/ μs
GBW Gain bandwidth product	⁽²⁾	25°C		6		MHz
Φ_m Phase margin	⁽²⁾	25°C		64.2		deg
Gain margin	⁽²⁾	25°C		8.7		dB
Amplifier-to-amplifier isolation	$V_{CC+} = 5 \text{ V}$, $R_L = 100 \text{ k}\Omega$ to 2.5 V ⁽³⁾	25°C		135		dB
V_n Equivalent input noise voltage	$f = 1 \text{ kHz}$, $V_{IC} = 1 \text{ V}$	25°C		42		nV/ $\sqrt{\text{Hz}}$
I_n Equivalent input noise current	$f = 1 \text{ kHz}$	25°C		0.2		pA/ $\sqrt{\text{Hz}}$
THD Total harmonic distortion	$f = 1 \text{ kHz}$, $A_V = -2$, $R_L = 10 \text{ k}\Omega$, $V_O = 4.1 \text{ V}_{\text{p-p}}$	25°C		0.01		%

(1) Connected as voltage follower with 3-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22 \text{ pF}$

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{\text{p-p}}$

LMV8xxI 5-V Electrical Characteristics
 $V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 2 \text{ V}$, $V_O = 2.5 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT	
			MIN	TYP	MAX		
V_{IO} Input offset voltage		25°C		1	3.5	mV	
		-40°C to 125°C			5.5		
α_{VIO} Average temperature coefficient of input offset voltage		25°C		1		μV/°C	
I_{IB} Input bias current		25°C		40	100	nA	
		-40°C to 125°C			150		
I_{IO} Input offset current		25°C		0.5	30	nA	
		-40°C to 125°C			50		
CMRR Common-mode rejection ratio	$V_{IC} = 0 \text{ to } 4 \text{ V}$	25°C	72	90		dB	
		-40°C to 125°C	70				
$+k_{SVR}$ Positive supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V to } 4 \text{ V}$, $V_{CC-} = -1 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	75	85		dB	
		-40°C to 125°C	70				
$-k_{SVR}$ Negative supply-voltage rejection ratio	$V_{CC+} = 1.7 \text{ V}$, $V_{CC-} = -1 \text{ V to } -3.3 \text{ V}$, $V_O = 0$, $V_{IC} = 0$	25°C	73	85		dB	
		-40°C to 125°C	70				
V_{ICR} Common-mode input voltage range	$CMRR \geq 50 \text{ dB}$	25°C	-0.2 to 4.2	-0.3 to 4.3		V	
A_v Large-signal voltage amplification	$R_L = 600 \Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	25°C	95	105	dB	
			-40°C to 125°C	90			
	$R_L = 600 \Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	95	105		
			-40°C to 125°C	90			
	$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 4.5 \text{ V}$	Sourcing	25°C	95	105		
			-40°C to 125°C	90			
	$R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$, $V_O = 2.5 \text{ V to } 0.5 \text{ V}$	Sinking	25°C	95	105		
			-40°C to 125°C	90			
V_O Output swing	$V_{CC+} = 5 \text{ V}$, $R_L = 600 \Omega \text{ to } 2.5 \text{ V}$	High level	25°C	4.75	4.84	V	
			-40°C to 125°C	4.6			
		Low level	25°C		0.17		
			-40°C to 125°C		0.3		
	$V_{CC+} = 5 \text{ V}$, $R_L = 2 \text{ k}\Omega \text{ to } 2.5 \text{ V}$	High level	25°C	4.85	4.9		
			-40°C to 125°C	4.8			
		Low level	25°C		0.1		
			-40°C to 125°C		0.2		
I_O Output current	$V_O = 0 \text{ V}$	Sourcing	25°C	20	45	mA	
			-40°C to 125°C	15			
	$V_O = 5 \text{ V}$	Sinking	25°C	20	40		
			-40°C to 125°C	15			
I_{CC} Supply current	LMV821		25°C		0.3	mA	
			-40°C to 125°C		0.6		
	LMV822 (both amplifiers)		25°C		0.5		
			-40°C to 125°C		0.9		
	LMV824 (all four amplifiers)		25°C	1	1.3		
			-40°C to 125°C		1.5		

LMV8xxI 5-V Electrical Characteristics (continued)

$V_{CC+} = 5 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{IC} = 2 \text{ V}$, $V_O = 2.5 \text{ V}$, and $R_L > 1 \text{ M}\Omega$ (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T_A	LMV821/822/824			UNIT
			MIN	TYP	MAX	
SR Slew rate	$V_{CC+} = 5 \text{ V}$ ⁽¹⁾	25°C	1.4	1.9		V/ μs
GBW Gain bandwidth product	⁽²⁾	25°C		6		MHz
Φ_m Phase margin	⁽²⁾	25°C		64.2		deg
Gain margin	⁽²⁾	25°C		8.7		dB
Amplifier-to-amplifier isolation	$V_{CC+} = 5 \text{ V}$, $R_L = 100 \text{ k}\Omega$ to 2.5 V ⁽³⁾	25°C		135		dB
V_n Equivalent input noise voltage	$f = 1 \text{ kHz}$, $V_{IC} = 1 \text{ V}$	25°C		42		nV/ $\sqrt{\text{Hz}}$
I_n Equivalent input noise current	$f = 1 \text{ kHz}$	25°C		0.2		pA/ $\sqrt{\text{Hz}}$
THD Total harmonic distortion	$f = 1 \text{ kHz}$, $A_V = -2$, $R_L = 10 \text{ k}\Omega$, $V_O = 4.1 \text{ V}_{\text{p-p}}$	25°C		0.01		%

(1) Connected as voltage follower with 3-V step input. Value specified is the slower of the positive and negative slew rates.

(2) 40-dB closed-loop dc gain, $C_L = 22 \text{ pF}$

(3) Each amplifier excited in turn with 1 kHz to produce $V_O = 3 \text{ V}_{\text{p-p}}$

TYPICAL CHARACTERISTICS

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)

SUPPLY CURRENT
VS
SUPPLY VOLTAGE

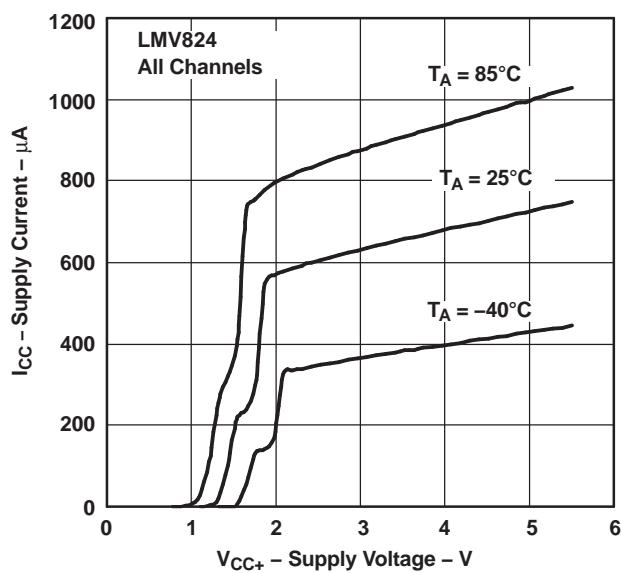


Figure 1.

INPUT CURRENT
VS
TEMPERATURE

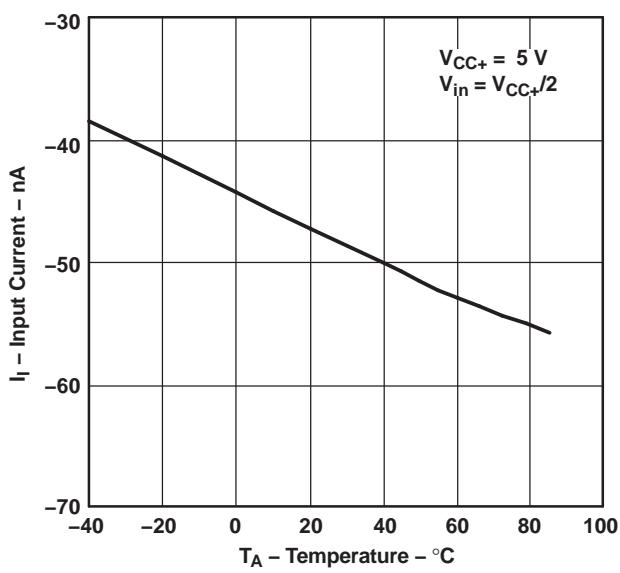


Figure 2.

SOURCING CURRENT
VS
OUTPUT VOLTAGE

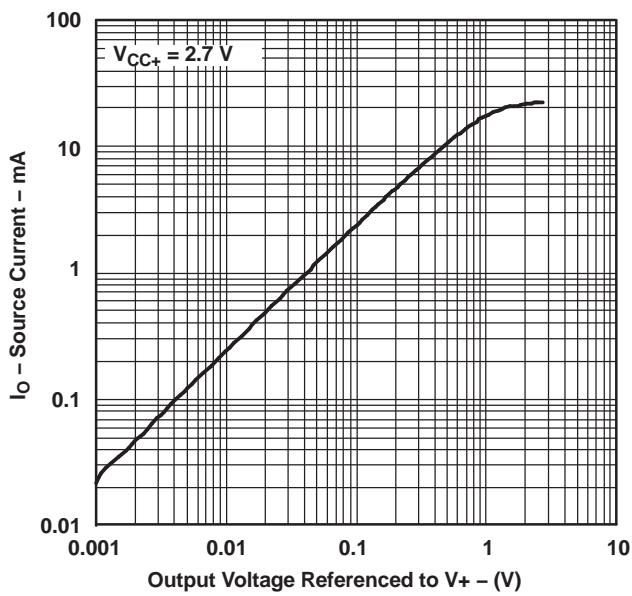


Figure 3.

SOURCING CURRENT
VS
OUTPUT VOLTAGE

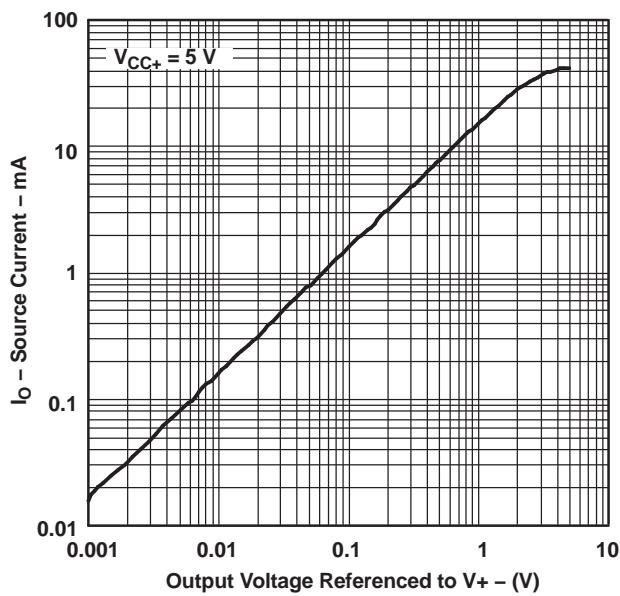


Figure 4.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V}$ Single Supply (Unless Otherwise Noted)

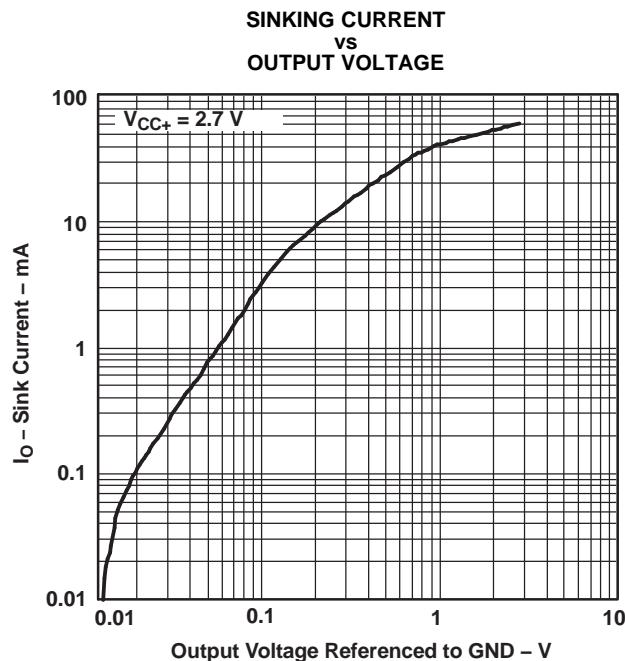


Figure 5.

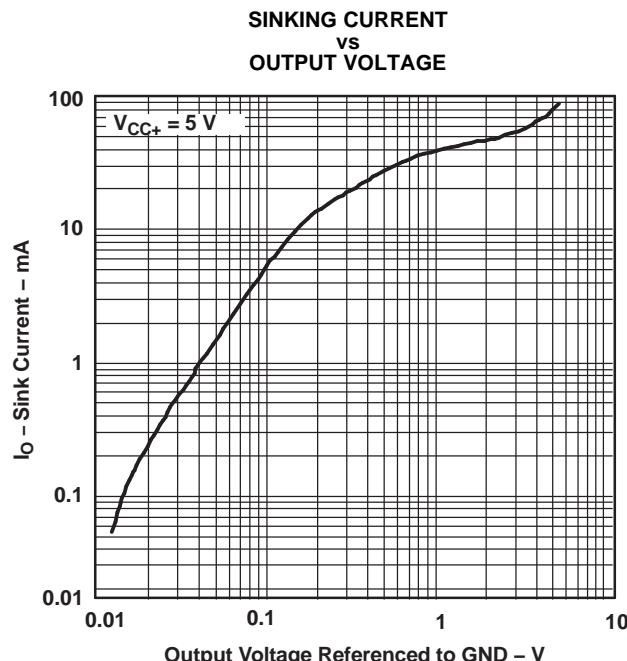


Figure 6.

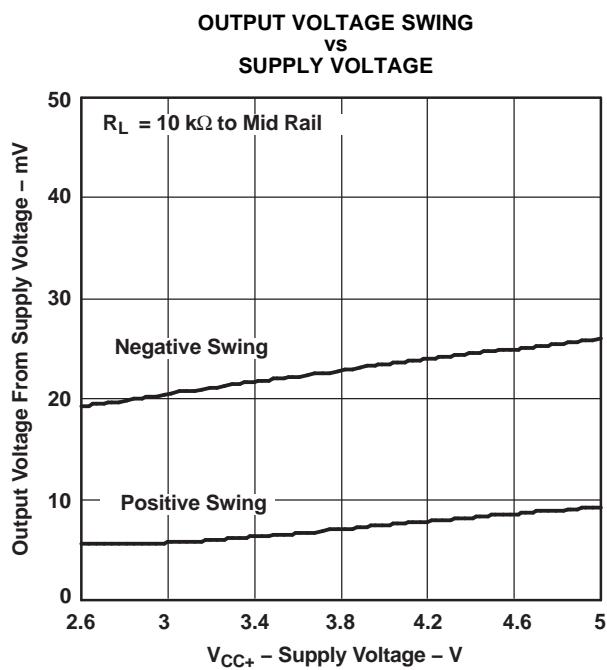


Figure 7.

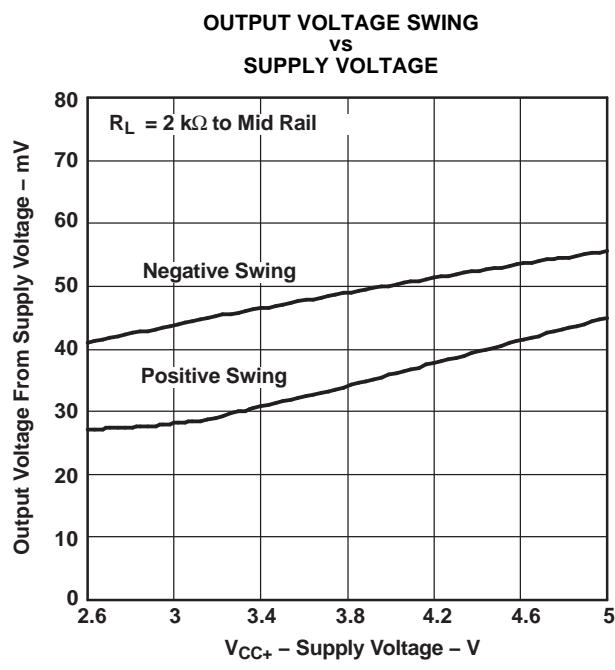


Figure 8.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)

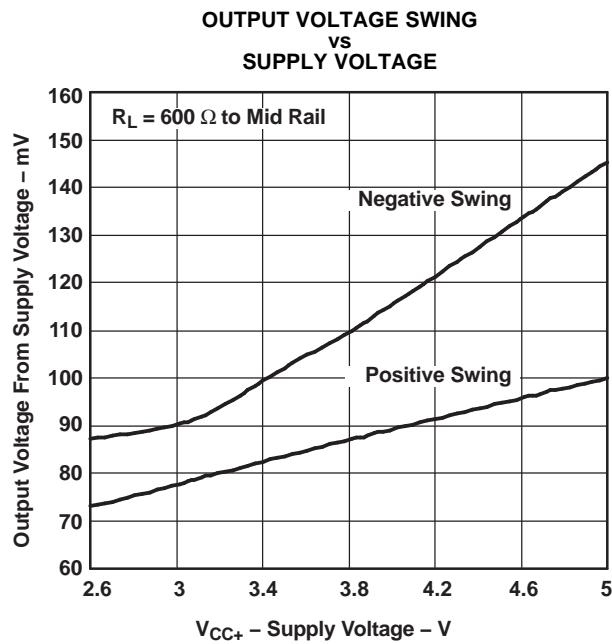


Figure 9.

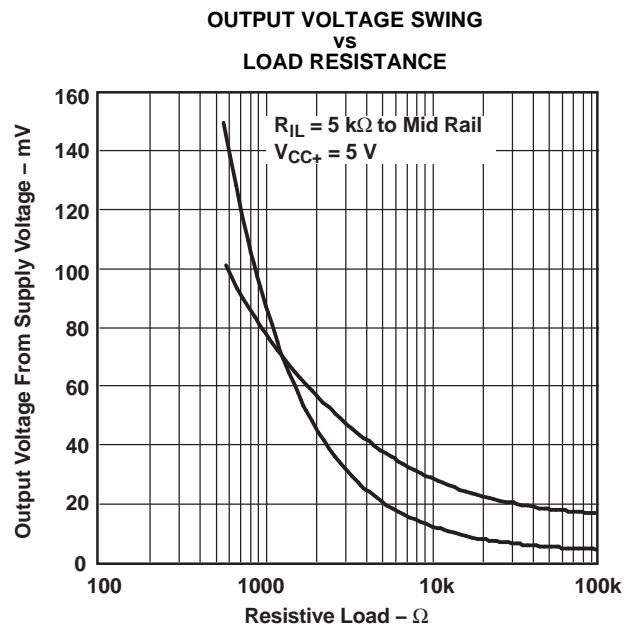


Figure 10.

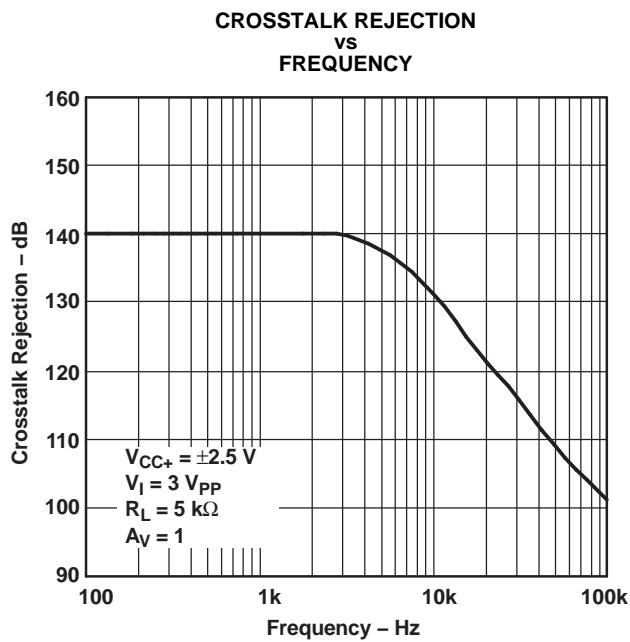


Figure 11.

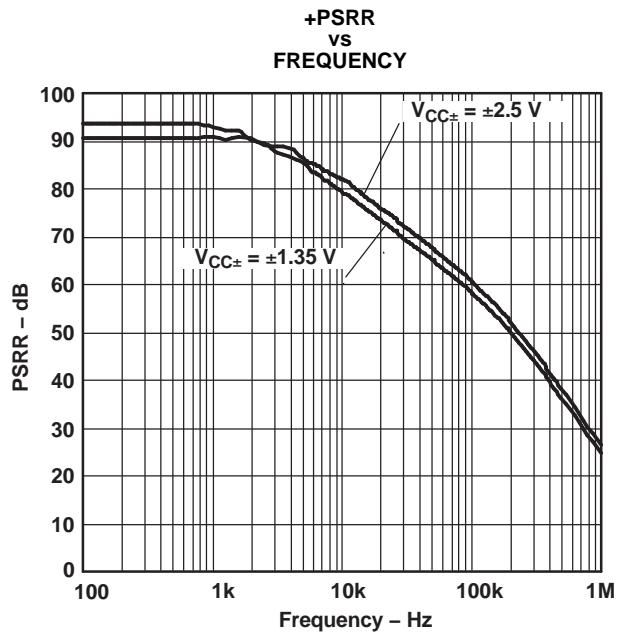


Figure 12.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)

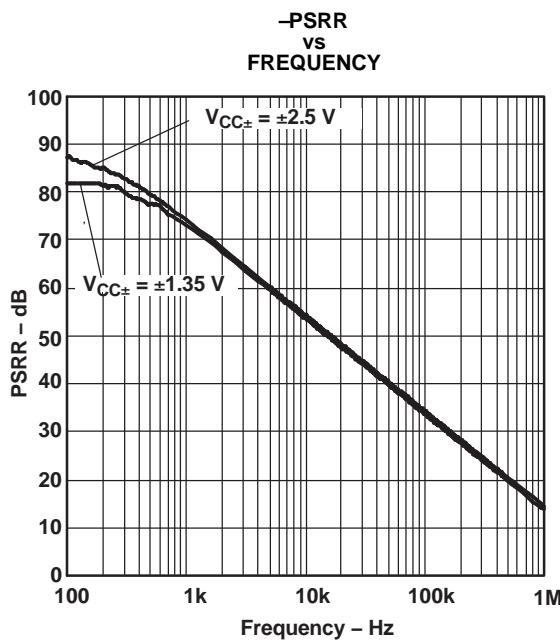


Figure 13.

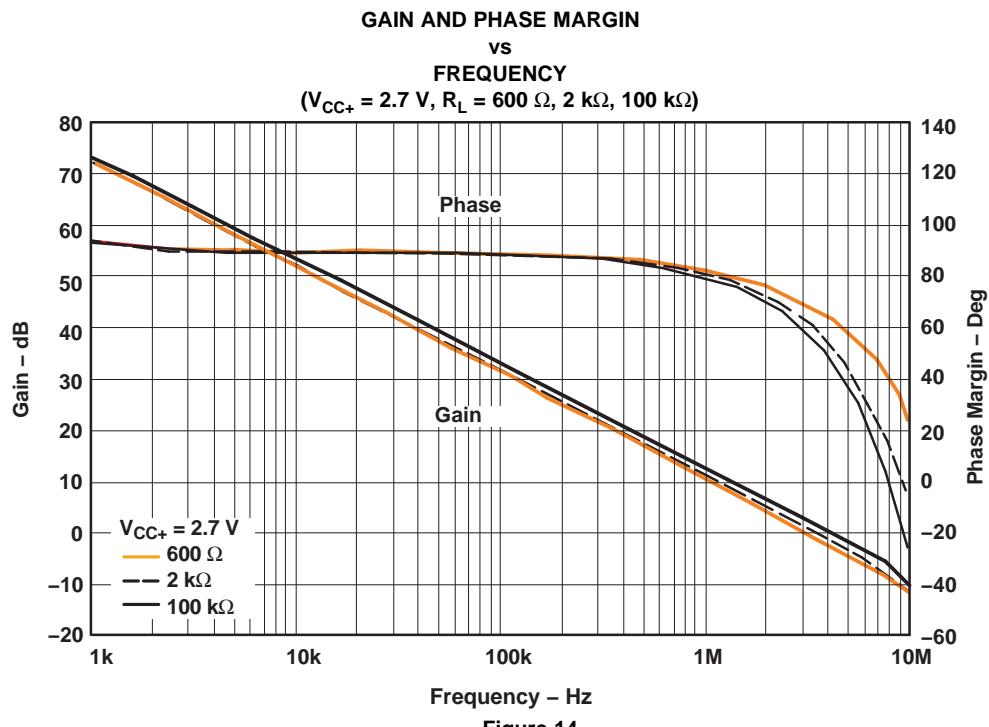


Figure 14.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)

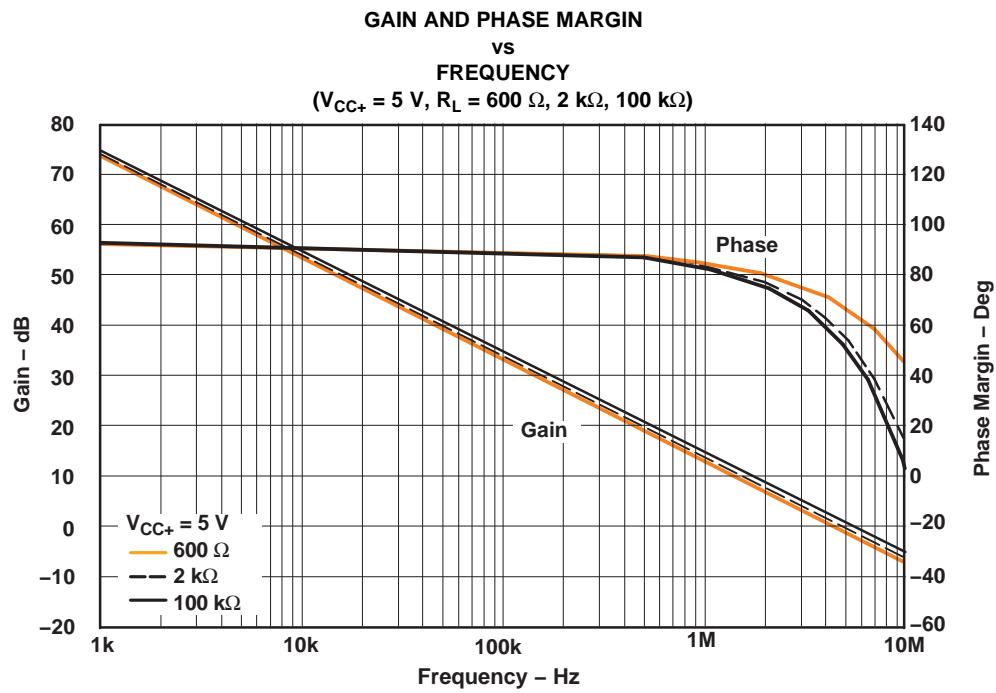


Figure 15.

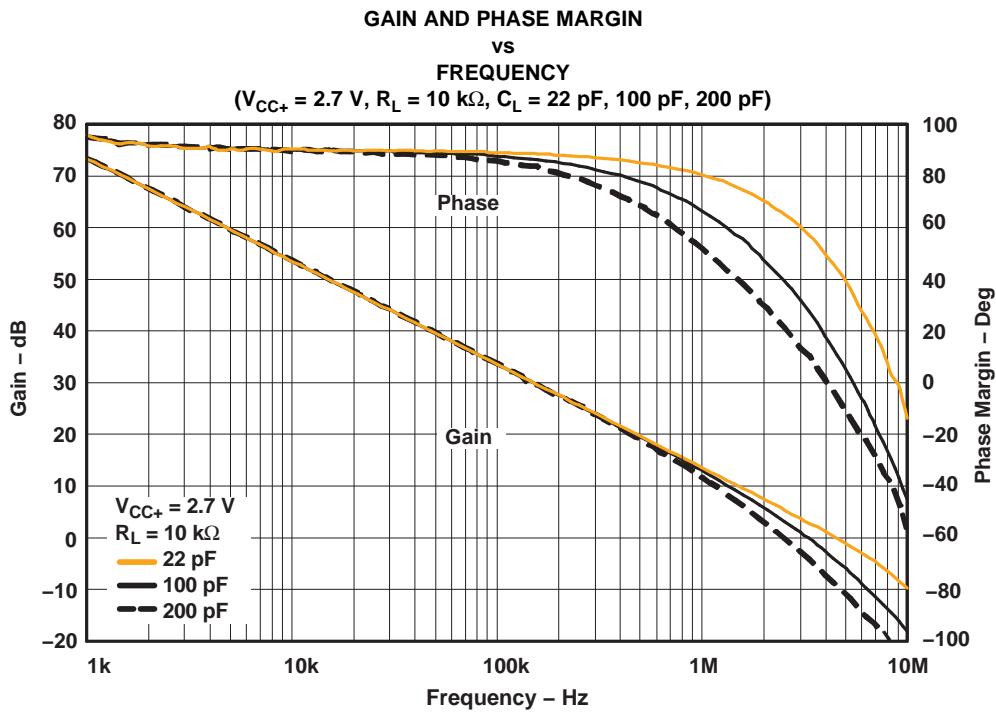
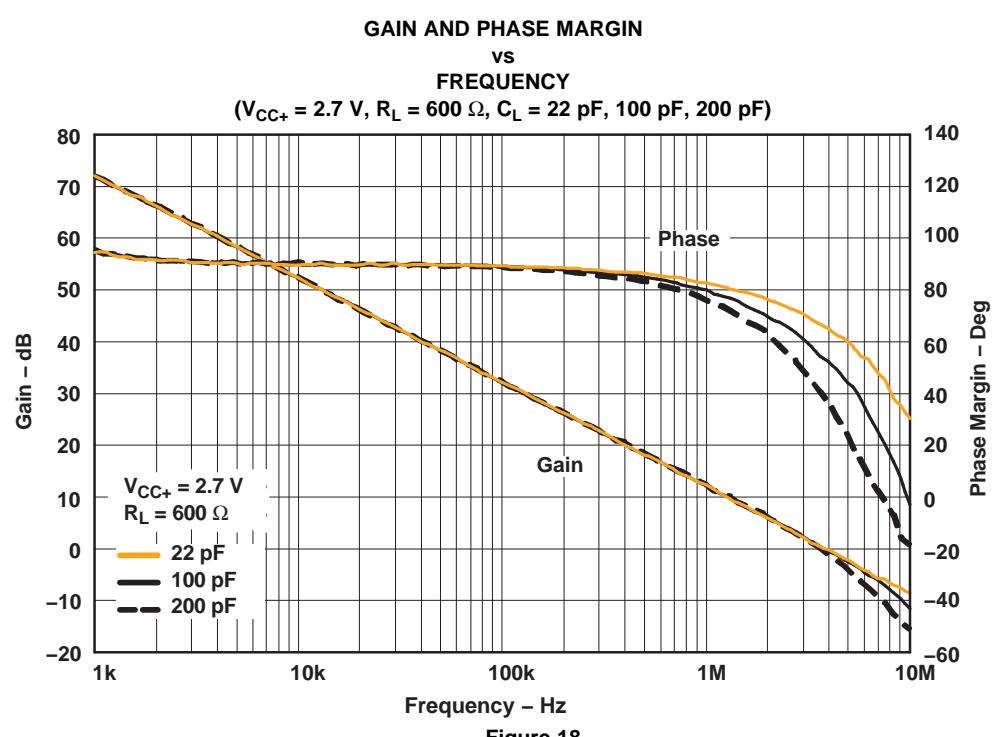
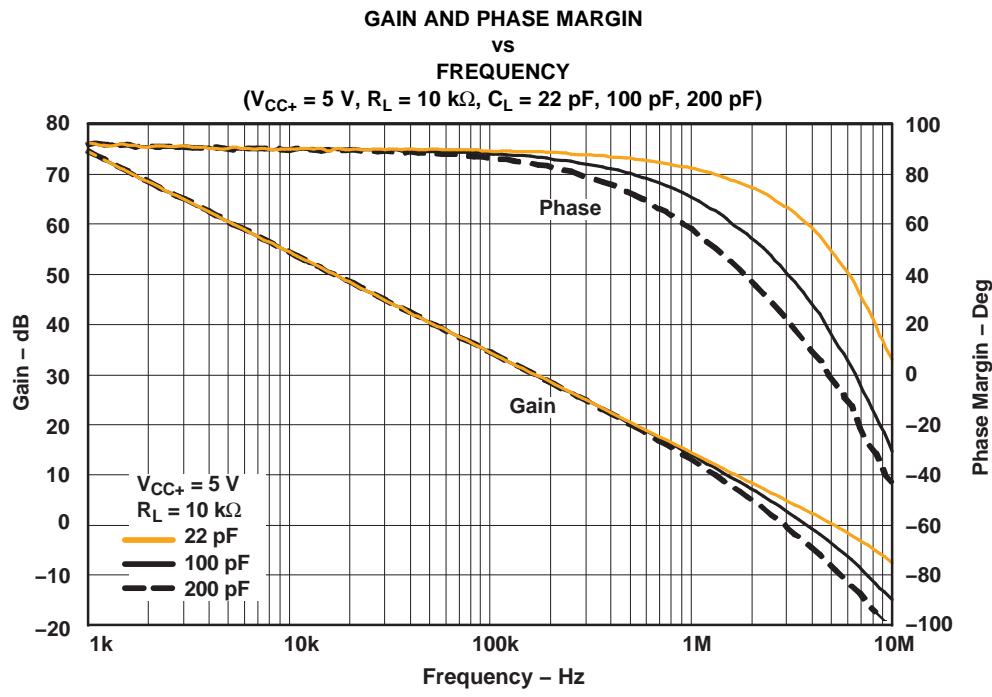


Figure 16.

TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)



TYPICAL CHARACTERISTICS (continued)

$T_A = 25^\circ\text{C}$, $V_{CC+} = 5\text{-V Single Supply}$ (Unless Otherwise Noted)

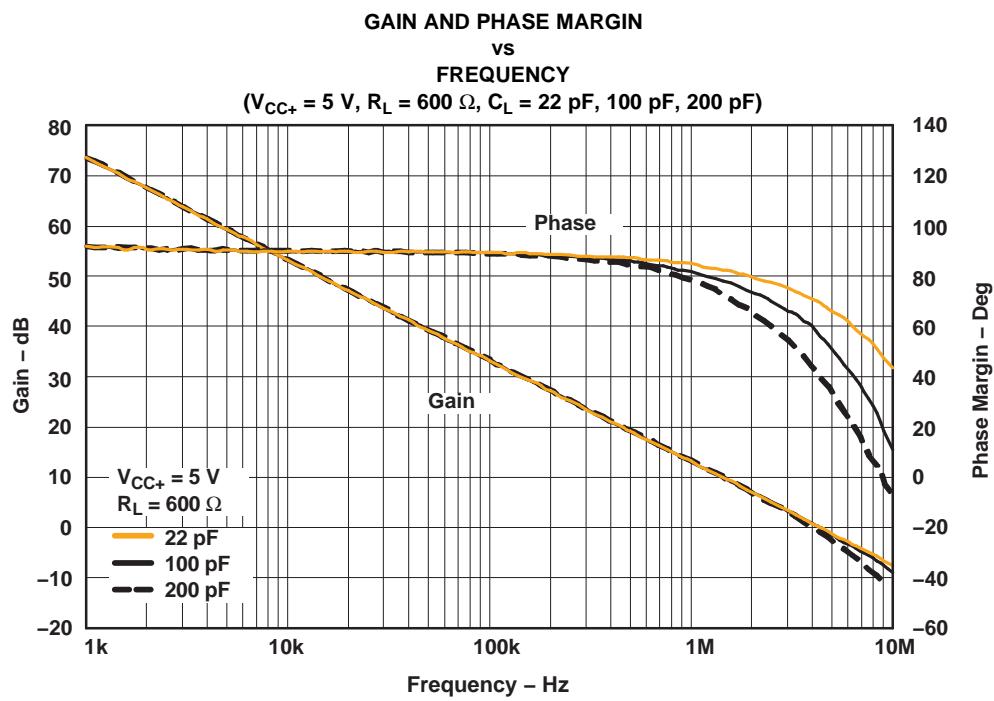


Figure 19.

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